



Silicon Press-fit diodes

Silicon Protectifiers with TVS characteristics
High-temperature diodes
BYZ 35A22 ...BYZ 35K39

Pulse Power Dissipation: 8000 W
Maximum Stand-off voltage: / V

Publish Data

Features

- High power diodes
- High temperature diodes

Mechanical Data

- Metal press-fit case with plastic cover
- Casting compound has UL classification 94V-0
- Terminals - Ni plated
- Mounting position : any
- Weight approx. : 10 g
- Standard packing : Bulk
- BYZ35Axx - anode on wire
- BYZ35Kxx - cathode on wire

Absolute Maximum Ratings			
Symbol	Conditions	Values	Units
P_{PPM}	Peak pulse power dissipation $t_p = 1\text{ms}$ $T_a = 25^\circ\text{C}$	8000	W
$P_{M(AV)}$	Steady state power dissipation ²⁾ , $T_a = ^\circ\text{C}$		W
I_{FSM}	Peak forward surge current 50Hz half sin wave, $T_A = 25^\circ\text{C}$ $T_a = ^\circ\text{C}$	270	A
R_{thA}	Max. thermal resistance junction to ambient ²⁾		K/W
R_{thT}	Max. thermal resistance junction to terminal	0,8	K/W
T_j	Operating junction temperature	-50 ... +225	$^\circ\text{C}$
T_s	Storage temperature	-50 ... +225	$^\circ\text{C}$
V_f	Max. instant. forw. voltage $I_f = 100\text{A}$ ³⁾	<1,2 (BYZ 35A(K)22; 26)	V
		<1,3 (BYZ 35A(K)32; 36; 39)	V

Type	Characteristics						
	Max stand-off voltage@ I_D		Breakdown voltage@ I_T		Test current I_T	Max. clamping voltage@ I_{PPM}	
	V_{WM} V	I_D μA	min. V	max. V		V_C V	I_{PPM} A
BYZ 35A(K)22	16	10	20	25	100	35	80
BYZ 35A(K)27	20	10	25	29	100	40	80
BYZ 35A(K)33	26	10	31	35	100	50	60
BYZ 35A(K)37	30	10	34	40	100	56	60
BYZ 35A(K)39	32	10	35	43	100	58	50

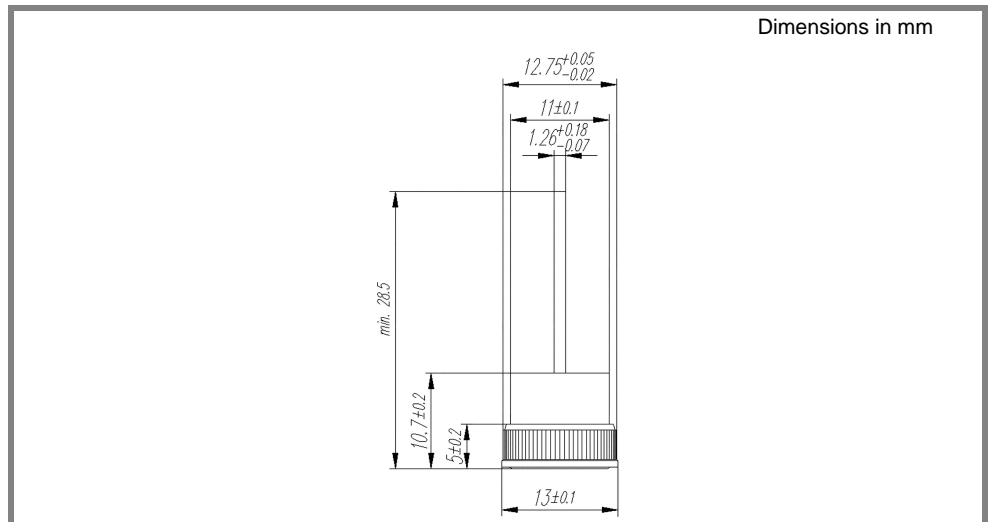


Fig. 1